

Roll No.

OLE-3003

B. Tech. 1st Semester (CSE) Examination – April, 2021

SEMICONDUCTOR PHYSICS

Paper : BSC-PHY-103-G

Time : Three Hours]

[Maximum Marks : 75

Before answering the questions, candidates should ensure that they have been supplied the correct and complete question paper. No complaint in this regard, will be entertained after examination.

Note : Attempt *five* questions in all, selecting *one* question from each Unit. Question No. 1 is *compulsory*. All questions carry equal marks.

1. (a) Explain the term effective mass.
- (b) Discuss the formation of depletion layer in semiconductor diode.
- (c) What do you mean by drift velocity ?
- (d) Semiconductors have negative temperature coefficient of resistance. Explain its meaning.
- (e) Write a short note on photovoltaic effect.
- (f) What do you mean by a phonon ? $6 \times 2.5 = 15$

UNIT – I

2. What is the effect of periodic potential on the energy of electron in a metal? Explain it on the basis of Kronig penny model. 15
3. (a) Discuss the motion of a free electron in one dimensional potential box and derive expressions for eigen wave function and eigen state. 10
- (b) What is Fermi energy and calculate its value for free electron gas at 0°K ? 5

UNIT – II

4. Derive an expression for the carrier concentration in intrinsic semiconductors. What would be the position of Fermi level ? Explain. 15
5. (a) Write a short note on Metal semiconductor junction (Ohmic and Schottky). 8
- (b) Explain drift and diffusion current in semiconductors. 7

UNIT – III

6. (a) Explain Fermi golden rule for transition rates. 10
- (b) On account of optical transition define term absorption, spontaneous emission and stimulated emission. 5

7. Drive an expression for joint density of state of photons. 15

UNIT – IV

8. Describe four probe method with neat diagram to determine resistivity of a semiconductor crystal. 15
9. (a) Explain the concept of quantum well, wire and dot and derive the density of states. 10
- (b) Write short note on DLTS. 5
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